

Data Sheet

CentralTM Semiconductor Corp.

145 Adams Avenue, Hauppauge, NY 11788 USA
Tel: (631) 435-1110 • Fax: (631) 435-1824

Manufacturers of World Class Discrete Semiconductors

CBR10-010P SERIES
CBR25-010P SERIES
CBR35-010P SERIES

SILICON BRIDGE RECTIFIER

10 THRU 35A, 100 THRU 1000V

DESCRIPTION

The CENTRAL SEMICONDUCTOR CBR10, CBR25, CBR35 series types are silicon single phase full wave bridge rectifiers designed for general purpose applications. The molded epoxy case has a built-in metal baseplate for heat sink mounting. The plastic material is covered by UL flammability classification 94V-0. "P" Suffix device utilizes standard 0.25" fast on connectors. Wire leaded devices available by adding "W" to part number (Ex: CBR35-060PW). All Devices are UL recognized (File No. E130224).

MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

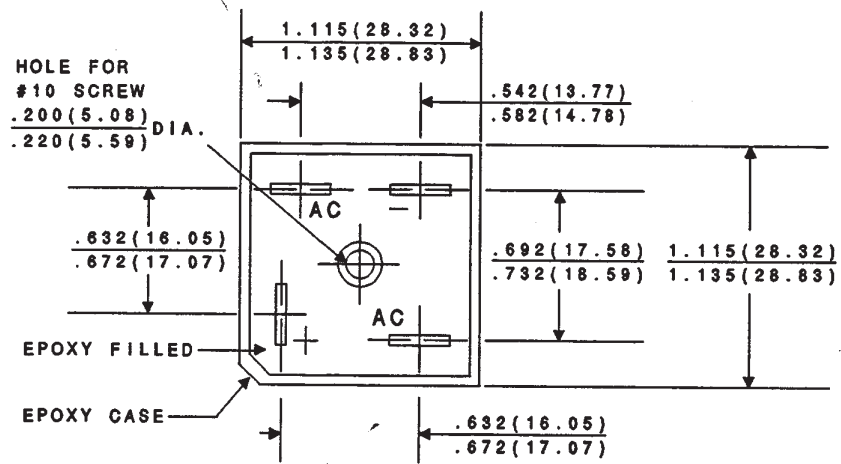
	SYMBOL	-010P	-020P	-040P	-060P	-080P	-100P	UNITS
Peak Repetitive Reverse Voltage	V _{RRM}	100	200	400	600	800	1000	V
DC Blocking Voltage	V _R	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	70	140	280	420	560	700	V
Average Forward Current (T _C =60°C) I _O								
	CBR10-010P SERIES				10			A
	CBR25-010P SERIES				25			A
	CBR35-010P SERIES				35			A
Peak Forward Surge Current (JEDEC) I _{FSM}								
	CBR10-010P SERIES				200			A
	CBR25-010P SERIES				350			A
	CBR35-010P SERIES				400			A
I ² t Rating for Fusing (1ms<t<8.3ms) I ² t								
	CBR10-010P SERIES				160			A ² sec
	CBR25-010P SERIES				375			A ² sec
	CBR35-010P SERIES				660			A ² sec
Typical Thermal Resistance	θ _{JC}							
	CBR10-010P SERIES				1.9			°C/W
	CBR25-010P SERIES				1.9			°C/W
	CBR35-010P SERIES				1.4			°C/W
Operating and Storage Junction Temperature	T _J , T _{stg}				-65 to +150			°C
RMS Isolation Voltage (case to leads)	V _{iso}				2500			V _{ac}

ELECTRICAL CHARACTERISTICS Per Diode (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	TYP	MAX	UNITS
V _F	I _F =1/2 Rated I _O		1.2	V
I _R	V _R =Rated V _{RRM}		10	μA
I _R	V _R =Rated V _{RRM} , T _A =125°C		500	μA
C _J	V _R =4.0V, f=1.0MHz	300		pF



CASE FP - MECHANICAL OUTLINE



CASE FPW - MECHANICAL OUTLINE

